TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC7SG02FE

#### 2-Input NOR Gate

#### **Features**

• High output current : ±8 mA (min) at V<sub>CC</sub> = 3.0 V

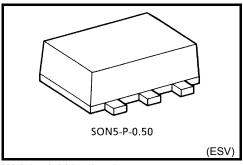
• Super high speed operation :  $t_{pd}$  = 2.4 ns (typ.)

at V<sub>CC</sub> = 3.3 V,15pF

• Operating voltage range : V<sub>CC</sub> = 0.9 to 3.6 V

5.5-V tolerant inputs

• 3.6-V power down protection output

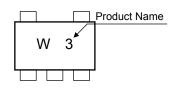


Weight: 0.003 g (typ.)

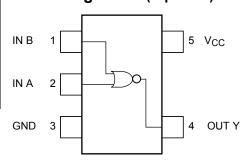
## Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Supply voltage	V <sub>CC</sub>	−0.5 to 4.6	V
DC input voltage	V <sub>IN</sub>	−0.5 to 7.0	V
DC output voltage	Vour	-0.5 to 4.6 (Note 1)	V
DC output voltage	Vout	-0.5 to V <sub>CC</sub> + 0.5 (Note 2)	
Input diode current	I <sub>IK</sub>	-20	mA
Output diode current	lok	-20 (Note 3)	mA
DC output current	lout	±25	mA
DC V <sub>CC</sub> /ground current	Icc	±50	mA
Power dissipation	PD	150	mW
Storage temperature	T <sub>stg</sub>	-65 to 150	°C

#### Marking



### Pin Assignment (top view)



Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1:  $V_{CC} = 0V$ 

Note 2: High or Low state. Do not exceed I<sub>OUT</sub> of absolute maximum ratings.

Note 3: V<sub>OUT</sub> < GND

Start of commercial production 2005-02

# **IEC Logic Symbol**

## **Truth Table**



Α	В	Υ
L	L	Н
L	Н	L
Н	L	L
Н	Н	L

# **Operating Ranges**

Characteristics	Symbol	Rating	Unit	
Supply voltage	V <sub>CC</sub>	0.9 to 3.6	V	
Input voltage	V <sub>IN</sub>	0 to 5.5	V	
Output voltage	V	0 to 3.6 (Note 4)	V	
	V <sub>OUT</sub>	0 to V <sub>CC</sub> (Note 5)	\ \ \	
		± 8.0 (Note 6)	mA	
	IOH/IOL -	± 4.0 (Note 7)		
Output Current		± 3.0 (Note 8)		
		± 1.7 (Note 9)	IIIA	
		± 0.3 (Note 10)		
		± 0.02 (Note 11)		
Operating temperature	T <sub>opr</sub>	-40 to 85	°C	
Input rise and fall time	dt/dv	0 to 10 (Note 12)	ns/V	

Note 4:  $V_{CC} = 0V$ 

Note 5: High or Low state.

Note 6:  $V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$ 

Note 7:  $V_{CC} = 2.3 \text{ to } 2.7 \text{ V}$ 

Note 8:  $V_{CC} = 1.65 \text{ to } 1.95 \text{ V}$ 

Note 9:  $V_{CC} = 1.4 \text{ to } 1.6 \text{ V}$ 

Note 10:  $V_{CC} = 1.1 \text{ to } 1.3 \text{ V}$ 

Note 11:  $V_{CC} = 0.9 V$ 

Note 12:  $V_{IN} = 0.8$  to 2.0 V,  $V_{CC} = 3.0$  V

## **Electrical Characteristics**

#### **DC Characteristics**

01 1 11		T 10 111			Ta = 25°C			Ta = -40 to 85°C		Unit
Characteristics Symbol Tes		Condition	V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	Unit	
					$V_{CC}$	_	_	V <sub>CC</sub>	_	
				1.1 to 1.3	V <sub>CC</sub> × 0.7	_	_	V <sub>CC</sub> × 0.7	_	
High-level input VIH	V <sub>IH</sub>	_		1.4 to 1.6	V <sub>CC</sub> × 0.65	ı	_	V <sub>CC</sub> × 0.65	_	V
voltage				1.65 to 1.95	V <sub>CC</sub> × 0.65	l		V <sub>CC</sub> × 0.65		
				2.3 to 2.7	1.7	_	_	1.7	_	
				3.0 to 3.6	2.0	_	_	2.0	_	
					_	_	GND	_	GND	V
					_	_	V <sub>CC</sub> × 0.3	_	V <sub>CC</sub> × 0.3	
Low-level input voltage	V <sub>IL</sub>	_		1.4 to 1.6	_	_	V <sub>CC</sub> × 0.35	_	V <sub>CC</sub> × 0.35	
Voltage				1.65 to 1.95		-	V <sub>CC</sub> × 0.35	_	V <sub>CC</sub> × 0.35	
				2.3 to 2.7			0.7	_	0.7	
				3.0 to 3.6			0.8	_	0.8	
			I <sub>OH</sub> =-0.02 mA	0.9	0.75	_	_	0.75	_	V
		V <sub>IN</sub> = V <sub>IL</sub>	I <sub>OH</sub> = -0.3 mA	1.1 to 1.3	V <sub>CC</sub> × 0.75	_	_	V <sub>CC</sub> × 0.75	_	
High-level output	V <sub>OH</sub>		I <sub>OH</sub> = -1.7 mA	1.4 to 1.6	V <sub>CC</sub> × 0.75	_	_	V <sub>CC</sub> × 0.75	_	
voltage			I <sub>OH</sub> = -3.0 mA	1.65 to 1.95	V <sub>CC</sub> -0.45	_	_	V <sub>CC</sub> -0.45	_	
			I <sub>OH</sub> = -4.0 mA	2.3 to 2.7	2.0		_	2.0	_	
			I <sub>OH</sub> = -8.0 mA	3.0 to 3.6	2.48	_	_	2.48	_	
		V <sub>OL</sub> V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 0.02 mA	0.9	_	_	0.1	_	0.1	V
			I <sub>OL</sub> = 0.3 mA	1.1 to 1.3	_	_	V <sub>CC</sub> × 0.25	_	V <sub>CC</sub> × 0.25	
Low-level output voltage Vol	V <sub>OL</sub>		I <sub>OL</sub> = 1.7 mA	1.4 to 1.6	_	_	V <sub>CC</sub> × 0.25	_	V <sub>CC</sub> × 0.25	
			I <sub>OL</sub> = 3.0 mA	1.65 to 1.95	_	_	0.45	_	0.45	
			I <sub>OL</sub> = 4.0 mA	2.3 to 2.7	_	_	0.4	_	0.4	
			I <sub>OL</sub> = 8.0 mA	3.0 to 3.6	_	_	0.4	_	0.4	
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = 0 to 5.5 V		0 to 3.6			±0.1	_	±1.0	μА
Power off leakage current	I <sub>OFF</sub>	V <sub>IN</sub> = 0 to 5.5 V V <sub>OUT</sub> = 0 to 3.6 V		0	_	_	1.0	_	10.0	μА
Quiescent supply current	Icc	V <sub>IN</sub> = V <sub>CC</sub> or GND		3.6	_	_	1.0	_	10.0	μΑ

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## AC Characteristics (unless otherwise specified, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = -40 to 85°C		Unit
Characteristics			V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	Offic
		C <sub>L</sub> = 10 pF,	0.9	_	17.0	_	_	_	
			1.1 to 1.3	_	8.8	18.4	1.0	34.2	
			1.4 to 1.6	_	5.0	8.5	1.0	10.0	
		$R_L = 1 M\Omega$	1.65 to 1.95	_	3.8	6.2	1.0	6.7	
			2.3 to 2.7	_	2.7	3.9	1.0	4.4	
	t <sub>р</sub> LH t <sub>р</sub> HL		3.0 to 3.6	_	2.1	3.1	1.0	3.7	
		$C_L$ = 15 pF, $R_L$ = 1 $M\Omega$	0.9	_	20.7	_	_	_	ns
			1.1 to 1.3	_	10.6	21.5	1.0	37.2	
Propagation delay time			1.4 to 1.6	_	5.9	9.3	1.0	11.2	
Topagation delay time			1.65 to 1.95	_	4.5	6.9	1.0	7.1	
			2.3 to 2.7	_	3.0	4.4	1.0	5.0	
			3.0 to 3.6	_	2.4	3.4	1.0	3.9	
		$C_L$ = 30 pF, $R_L$ = 1 $M\Omega$	0.9	_	29.6	_	_	_	
			1.1 to 1.3	_	14.8	29.6	1.0	56.0	
			1.4 to 1.6	_	8.0	13.1	1.0	15.9	
			1.65 to 1.95	_	6.0	9.2	1.0	9.6	
			2.3 to 2.7	_	3.9	5.7	1.0	6.1	
			3.0 to 3.6		3.0	4.4	1.0	4.8	
Input capacitance	C <sub>IN</sub>		3.6	_	3		_	_	pF
Power dissipation capacitance	$C_{PD}$	(Note 13)	0.9 to 3.6	_	6	_	_	_	pF

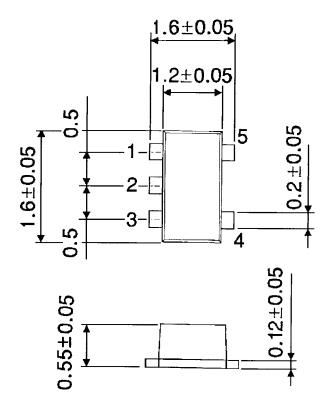
Note 13: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC (opr.)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$ 

# **Package Dimensions**

SON5-P-0.50 Unit: mm



Weight: 0.003 g (typ.)

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